



ABR5000 - ABR5010

PRV : 50 - 1000 Volts

Io : 50 Amperes

FEATURES :

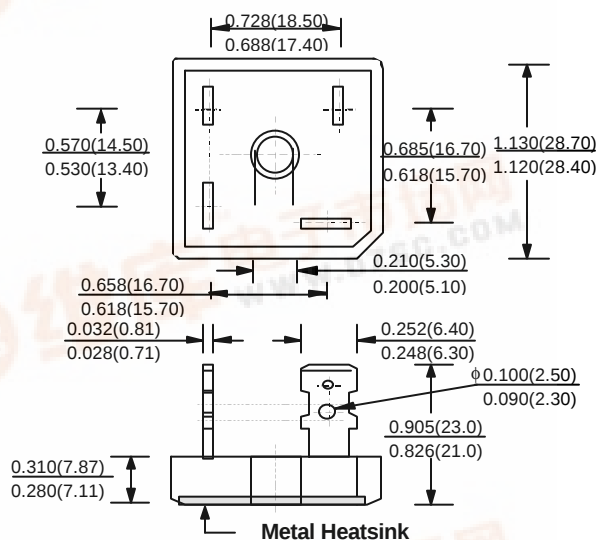
- * High case dielectric strength
- * High surge current capability
- * High reliability
- * Low reverse current
- * Low forward voltage drop
- * Ideal for printed circuit board

MECHANICAL DATA :

- * Case : Molded plastic with heatsink integrally mounted in the bridge encapsulation
- * Epoxy : UL94V-O rate flame retardant
- * Terminals : plated .025" (6.35 mm). Faston
- * Polarity : Polarity symbols marked on case
- * Mounting position : Bolt down on heat-sink with silicone thermal compound between bridge and mounting surface for maximum heat transfer efficiency.
- * Weight : 17.1 grams

AVALANCHE BRIDGE RECTIFIERS

BR50



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

RATING	SYMBOL	ABR 5000	ABR 5001	ABR 5002	ABR 5004	ABR 5006	ABR 5008	ABR 5010	UNIT
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Minimum Avalanche Breakdown Voltage at 100 μ A	$V_{BO(min.)}$	100	150	250	450	700	900	1100	Volts
Maximum Avalanche Breakdown Voltage at 100 μ A	$V_{BO(max.)}$	550	600	700	900	1150	1350	1550	Volts
Maximum Average Forward Current $T_c = 50^\circ\text{C}$	$I_{F(AV)}$	50							Amps.
Peak Forward Surge Current Single half sine wave Superimposed on rated load (JEDEC Method)	I_{FSM}	400							Amps.
Rating for fusing at ($t < 8.3$ ms.)	I^2t	660							A^2S
Maximum Forward Voltage per Diode at $I_F = 25$ Amps.	V_F	1.1							Volts
Maximum DC Reverse Current $T_a = 25^\circ\text{C}$	I_R	10							μ A
at Rated DC Blocking Voltage $T_a = 100^\circ\text{C}$	$I_{R(H)}$	200							μ A
Typical Thermal Resistance (Note 1)	$R_{\theta JC}$	1							$^\circ\text{C/W}$
Operating Junction Temperature Range	T_J	- 50 to + 150							$^\circ\text{C}$
Storage Temperature Range	T_{STG}	- 50 to + 150							$^\circ\text{C}$



RATING AND CHARACTERISTIC CURVES (ABR5000 - ABR5010)

FIG.1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

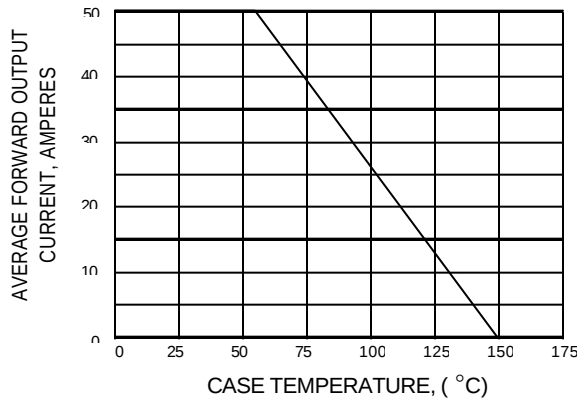


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

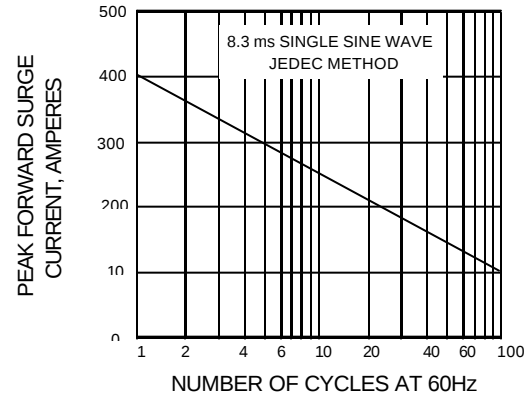


FIG.3 - TYPICAL FORWARD CHARACTERISTICS PER DIODE

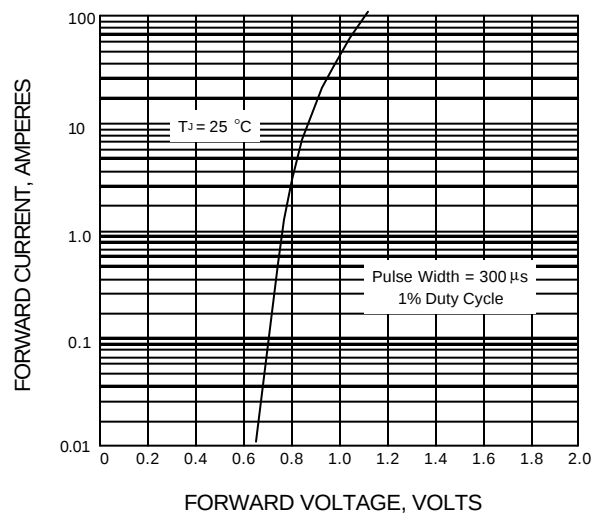


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

